



S/N 10/053,300

PATENT

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicant:	Vishnu K. Agarwal et al.	Examiner:	Hoai V Pham
Serial No.:	10/053,300	Group Art Unit:	2814
Filed:	January 17, 2002	Docket No.:	303.780US1
Title:	TRANSISTOR STRUCTURE HAVING REDUCED TRANSISTOR LEAKAGE ATTRIBUTES		

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AMENDMENT AND RESPONSE UNDER 37 CFR § 1.111

Mail Stop Amendment  
Commissioner for Patents  
P.O. Box 1450  
Alexandria, VA 22313-1450

This responds to the Office Action mailed on October 28, 2005. Please amend the above-identified patent application as follows.